# Dual Bidirectional I2C Bus and SMBus <br> Voltage－Level Translator 

## Datasheet（EN） 1.1

## Product Overview

The NCA9306 device is a dual bidirectional $\mathrm{I}^{2} \mathrm{C}$ and SMBus voltage－level translator with an enable（ EN ）input，and is operational from 1.2 V to $3.3 \mathrm{~V} \mathrm{~V}_{\text {Ref1 }}$ and 1.8 V to $5.5 \mathrm{~V} \mathrm{~V}_{\text {Ref2 }}$ ．

The NCA9306 device allows bidirectional voltage translations between 1.2 V and 5 V ，without the use of a direction pin．The low ON－state resistance（RoN）of the switch allows connections to be made with minimal propagation delay．When EN is high，the translator switch is ON，and the SCL1 and SDA1 I／O are connected to the SCL2 and SDA2 I／O，respectively，allowing bidirectional data flow between ports．When EN is low，the translator switch is off，and a high－impedance state exists between ports．

In addition to voltage translation，the NCA9306 device can be used to isolate a 400 kHz bus from a 100 kHz bus by controlling the EN pin to disconnect the slower bus during fast－mode communication．

## Key Features

－ 2 Bit bidirectional translator for SDA and SCL lines in mixed－mode ${ }^{2}$ C Applications
－$I^{2} \mathrm{C}$ and SMBus Compatible
－Less than 1.5 －ns Maximum Propagation Delay to Accommodate Standard－mode and Fast－mode $I^{2} \mathrm{C}$ Devices and Multiple Masters
－Allows Voltage－level Translation Between
$-1.2 \mathrm{~V} \mathrm{~V}_{\text {REF } 1}$ and $1.8 \mathrm{~V}, 2.5 \mathrm{~V}, 3.3 \mathrm{~V}$ ，or $5 \mathrm{~V}_{\text {REF2 }}$
$-1.8 \mathrm{~V} \mathrm{~V}_{\text {REF } 1}$ and $2.5 \mathrm{~V}, 3.3 \mathrm{~V}$ ，or $5 \mathrm{~V} \mathrm{~V}_{\text {REF2 }}$
$-2.5 \mathrm{~V} \mathrm{~V}_{\text {REF } 1}$ and 3.3 V or $5 \mathrm{~V} \mathrm{~V}_{\text {REF2 }}$
$-3.3 \mathrm{~V} \mathrm{~V}_{\text {Ref }}$ and $5 \mathrm{~V} \mathrm{~V}_{\text {Ref2 }}$
－Provides Bidirectional Voltage Translation with no Direction Pin
－Low $3.5 \Omega$ ON－state Resistance Between Input and Output Ports Provides Less Signal Distortion
－Open－drain $I^{2} \mathrm{C}$ I／O ports（SCL1，SDA1，SCL2，and SDA2）
－ 5 V Tolerant $I^{2} \mathrm{C}$ I／O Ports to Support Mixed－mode Signal Operation
－High－impedance SCL1，SDA1，SCL2，and SDA2 pins for EN ＝Low
－Lockup－free Operation for Isolation when $\mathrm{EN}=$ Low
－Flow－through Pinout for Ease of Printed－circuit board Trace Routing
－Latch－up Performance Exceeds 100 mA Per JESD 78，Class II
－ESD Protection Exceeds JESD 22
－2000V Human－Body Model（A114－A）
－1000V Charged－Device Model（C101）

## Applications

－${ }^{2}$ ²，SMBus，PMBus，MDIO，UART，low－speed SDIO，GPIO， and other two－signal interfaces
－Servers
－Routers（Telecom Switching Equipment）
－Personal Computers
－Industrial Automation

## Device Information

| Part Number | Package | Body Size |
| :--- | :--- | :--- |
| NCA9306－DVSR | VSSOP8 | $2.00 \mathrm{~mm} \times 2.30 \mathrm{~mm}$ |
| NCA9306－DTSHR | TSSOP8 | $3.00 \mathrm{~mm} \times 3.00 \mathrm{~mm}$ |

## Functional Block Diagrams



Figure 1．NCA9306 Block Diagram

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## 1. Pin Configuration and Functions



Figure 1.1 NCA9306 Package

Table 1.1 Pin Configuration and Description

| Symbol | Pin | Description |
| :---: | :---: | :---: |
| GND | 1 | Ground, 0 V |
| V $_{\text {REF1 }}$ | 2 | Low-voltage-side reference supply voltage for SCL1 and SDA1 |
| SCL1 | 3 | Serial clock, low-voltage side |
| SDA1 | 4 | Serial data, low-voltage side |
| SDA2 | 5 | Serial data, high-voltage side |
| SCL2 | 6 | Serial clock, high-voltage side |
| V $_{\text {REF2 }}$ | 7 | High-voltage-side reference supply voltage for SCL2 and SDA2 |
| EN | 8 | Switch enable input |

## 2. Absolute Maximum Ratings

| Parameters | Symbol | Min | Typ | Max | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Reference Voltage(1) | $\mathrm{V}_{\text {REF1 }}$ | -0.5 |  | 6 | V |  |
| Reference bias Voltage(2) | $\mathrm{V}_{\text {bias(REF2) }}$ | -0.5 |  | 6 | V |  |
| Input/output Voltage | $\mathrm{V}_{1} / \mathrm{V}_{0}$ | -0.5 |  | 6 | V |  |
| Input clamp current | $\mathrm{I}_{\text {K }}$ |  |  | -50 | mA | $\mathrm{V}_{1}<0 \mathrm{~V}$ |
| channel current (DC) | $\mathrm{I}_{\mathrm{CH}}$ |  |  | 128 | mA |  |
| Operating Temperature | $\mathrm{T}_{\text {opr }}$ | -40 |  | 85 | ${ }^{\circ} \mathrm{C}$ |  |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ | -40 |  | 150 | ${ }^{\circ} \mathrm{C}$ |  |
| Electrostatic discharge | HBM |  |  | $\pm 2000$ | V |  |
|  | CDM |  |  | $\pm 1000$ | V |  |

## 3. Recommended Operating Conditions

| Parameters | Symbol | Min | Max | Unit | Conditions |
| :--- | :--- | :--- | :--- | :--- | :--- |


| Input/output voltage | $\mathrm{V}_{10}$ | 0 | 5.5 | V | SCL1,SDA1,SCL2,SDA2 |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Reference voltage $^{1}$ | $\mathrm{~V}_{\text {REF1 }}$ | 0 | 5.5 | V |  |
| Reference voltage $^{1}$ | $\mathrm{~V}_{\text {REF2 }}$ | 0 | 5.5 | V |  |
| Enable input voltage | EN | 0 | 5.5 | V |  |
| Pass switch current | $\mathrm{I}_{\text {PASS }}$ | - | 64 | mA |  |
| Operating ambient <br> temperature | $\mathrm{T}_{\mathrm{A}}$ | -40 | 85 | ${ }^{\circ} \mathrm{C}$ |  |

## 4. Thermal Information

| Parameters | Symbol | VSSOP8 | TSSOP8 | Unit |
| :--- | :---: | :---: | :---: | :---: |
| IC Junction-to-Air Thermal Resistance | $\theta_{\mathrm{JA}}$ | 210.1 | 189.6 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction-to-case (top) thermal <br> resistance | $\theta_{\mathrm{JC}}($ top | 81.9 | 119.6 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction-to-board thermal resistance | $\theta_{\mathrm{JB}}$ | 88.8 | 102.1 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## 5. Specifications

### 5.1. Electrical Characteristics

VCC $=1.6 \mathrm{~V}$ to $5.5 \mathrm{~V} ; \mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$; unless otherwise noted. Typical specification are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| Parameters | Symbol | Min | Typ | Max | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input clamp voltage | $\mathrm{V}_{\mathrm{IK}}$ | -1.2 |  |  | V | $\mathrm{I}_{1}=-18 \mathrm{~mA}, \mathrm{EN}=0$ |
| Input leakage current | $\mathrm{I}_{\mathrm{H}}$ | - | - | 1 | uA | $\mathrm{V}_{1}=5 \mathrm{~V}, \mathrm{EN}=0 \mathrm{~V}$ |
| Input capacitance | $\mathrm{C}_{\text {(EN) }}$ |  | 11 |  | pF | $\mathrm{V}_{1}=0 \mathrm{~V}$ or 3 V |
| Off capacitance | $\mathrm{C}_{\text {io(off }}$ | - | 4 | 6 | pF | $\mathrm{V}_{0}=0 \mathrm{~V}$ or $3 \mathrm{~V}, \mathrm{EN}=0 \mathrm{~V}$;SDAn, SCLn |
| On capacitance | $\mathrm{C}_{\text {io(on) }}$ | - | 10.5 | 12.5 | pF | $\mathrm{V}_{0}=0 \mathrm{~V}$ or $3 \mathrm{~V}, \mathrm{EN}=3 \mathrm{~V}$;SDAn,SCLn |
| On-state resistance;SDAn,SCLn ${ }^{1}$ | Ron ${ }^{2}$ |  | 1.6 | 3.0 | $\Omega$ | $\mathrm{V}_{1}=0, \mathrm{l}_{0}=64 \mathrm{~mA}, \mathrm{EN}=4.5 \mathrm{~V}$ |
|  |  |  | 2.0 | 4.0 | $\Omega$ | $\mathrm{V}_{1}=0, \mathrm{l}_{0}=64 \mathrm{~mA}, \mathrm{EN}=3 \mathrm{~V}$ |
|  |  |  | 2.6 | 5.0 | $\Omega$ | $\mathrm{V}_{1}=0, \mathrm{l}_{\mathrm{o}}=64 \mathrm{~mA}, \mathrm{EN}=2.3 \mathrm{~V}$ |
|  |  |  | 2.5 | 5.0 | $\Omega$ | $\mathrm{V}_{1}=0, \mathrm{l}_{0}=15 \mathrm{~mA}, \mathrm{EN}=1.5 \mathrm{~V}$ |
|  |  | 1 | 3.9 | 7.0 | $\Omega$ | $\mathrm{V}_{1}=2.4 \mathrm{~V}, \mathrm{I}_{0}=15 \mathrm{~mA}, \mathrm{EN}=4.5 \mathrm{~V}$ |
|  |  | 20 | 55 | 70 | $\Omega$ | $\mathrm{V}_{1}=2.4 \mathrm{~V}, \mathrm{I}_{0}=15 \mathrm{~mA}, \mathrm{EN}=3 \mathrm{~V}$ |
|  |  | 20 | 46 | 60 | $\Omega$ | $\mathrm{V}_{1}=1.7 \mathrm{~V}, \mathrm{I}_{0}=15 \mathrm{~mA}, \mathrm{EN}=2.3 \mathrm{~V}$ |

${ }^{1}$ Measured by the voltage drop between the SCL1 and SCL2, or SDA1 and SDA2 terminals at the indicated current through the switch.ON-state resistance is determined by the lowest voltage of the two terminals.
${ }^{2}$ Guaranteed by design.

### 5.2. Switching Characteristics AC Performance

## Translating Down

over recommended operating ambient temperature range, $\mathrm{EN}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{IH}}=3.3 \mathrm{~V}, \mathrm{~V}$ IL $=0, \mathrm{~V}_{\mathrm{M}}=1.15 \mathrm{~V}$ (unless otherwise noted) (see Figure 5.1). ${ }^{1,2}$

| PARAMETER | FROM | TO | $C_{L}=50 \mathrm{pF}$ |  | $C_{L}=30 \mathrm{pF}$ |  | $C_{L}=15 \mathrm{pF}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | max | min | max | min | max |  |
| $\mathrm{t}_{\mathrm{plh}}$ | SDA2/SCL2 | SDA1/SCL1 | 0 | 0.8 | 0 | 0.6 | 0 | 0.3 | ns |
| $\mathrm{t}_{\mathrm{phl}}$ |  |  | 0 | 1.2 | 0 | 1 | 0 | 0.5 |  |

over recommended operating ambient temperature range, $\mathrm{EN}=2.5 \mathrm{~V}, \mathrm{VIH}=3.3 \mathrm{~V}, \mathrm{VIL}=0, \mathrm{VM}=0.75 \mathrm{~V}$ (unless otherwise noted) (see Figure 5.1).

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $C_{L}=50 \mathrm{pF}$ |  | $C_{L}=30 \mathrm{pF}$ |  | $C_{L}=15 \mathrm{pF}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | max | min | max | min | max |  |
| $\mathrm{t}_{\mathrm{plh}}$ | SDA2/SCL2 | SDA1/SCL1 | 0 | 1 | 0 | 0.7 | 0 | 0.4 | ns |
| $\mathrm{t}_{\mathrm{phl}}$ |  |  | 0 | 1.3 | 0 | 1 | 0 | 0.6 |  |

[^0]${ }^{2}$ Guaranteed by design.

## Translating UP

over recommended operating ambient temperature range, $\mathrm{EN}=3.3 \mathrm{~V}, \mathrm{VIH}=2.3 \mathrm{~V}, \mathrm{VIL}=0, \mathrm{VT}=3.3 \mathrm{~V}, \mathrm{VM}=1.15 \mathrm{~V}, \mathrm{RL}=300 \Omega$ (unless otherwise noted) (see Figure 5.2) ${ }^{1,2}$.

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $C_{L}=50 \mathrm{pF}$ |  | $C_{L}=30 \mathrm{pF}$ |  | $C_{L}=15 \mathrm{pF}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | max | min | max | min | max |  |
| $\mathrm{t}_{\mathrm{plh}}$ | SDA1/SCL1 | SDA2/SCL2 | 0 | 0.9 | 0 | 0.6 | 0 | 0.4 | ns |
| $\mathrm{t}_{\text {phl }}$ |  |  | 0 | 1.4 | 0 | 1.1 | 0 | 0.7 |  |

over recommended operating ambient temperature range, $\mathrm{EN}=2.5 \mathrm{~V}, \mathrm{VIH}=2.3 \mathrm{~V}, \mathrm{VIL}=0, \mathrm{VT}=3.3 \mathrm{~V}, \mathrm{VM}=0.75 \mathrm{~V}, \mathrm{RL}=300 \Omega$ (unless otherwise noted) (see Figure 5.2).

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $C_{L}=50 \mathrm{pF}$ |  | $C_{L}=30 \mathrm{pF}$ |  | $C_{L}=15 \mathrm{pF}$ |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | max | min | max | min | max |  |
| $\mathrm{t}_{\mathrm{plh}}$ | SDA1/SCL1 | SDA2/SCL2 | 0 | 1 | 0 | 0.6 | 0 | 0.4 | ns |
| $\mathrm{t}_{\text {phl }}$ |  |  | 0 | 1.3 | 0 | 1.3 | 0 | 0.8 |  |

[^1]${ }^{2}$ Guaranteed by design.

### 5.3. Parameter Measurement Information


a) Current Source Configuration
b) Current Sink Configuration

Figure 5.1 Current Source and Current Sink Configurations for RON Measurements


Notes: A. $C_{L}$ includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristic : $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{o}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}} \leq 2 \mathrm{~ns}$.
C. The outputs are measured one at a time, with one transition per measurement.

Figure 5.2 Load Circuit for Outputs

## 6. Function Description

### 6.1. Overview

The NCA9306 device is a dual bidirectional $I^{2} C$ and SMBus voltage-level translator with an enable (EN) input and operates without use of a direction pin. The voltage supply range for $\mathrm{V}_{\text {REF }}$ is 1.2 V to 3.3 V and the supply range for $\mathrm{V}_{\text {REF2 }}$ is 1.8 V to 5.5 V .
The NCA9306 device can also be used to run two buses, one at $400-\mathrm{kHz}$ operating frequency and the other at $100-\mathrm{kHz}$ operating frequency. If the two buses are operating at different frequencies, the $100-\mathrm{kHz}$ bus must be disconnected by using the EN pin when the $400-\mathrm{kHz}$ operation of the main bus is required. If the master is running at 400 kHz , the maximum system operating frequency may be less than 400 kHz because of the delays added by the level shifter.

In $I^{2} \mathrm{C}$ applications, the bus capacitance limit of 400 pF restricts the number of devices and bus length. The capacitive load on both sides of the NCA9306 device must be taken into account when approximating the total load of the system, ensuring the sum of both sides is under 400 pF .

Both the SDA and SCL channels of the NCA9306 device have the same electrical characteristics, and there is minimal deviation from one output to another in voltage or propagation delay. This is a benefit over discrete transistor voltage-translation solutions, because the fabrication of the switch is symmetrical. The translator provides excellent ESD protection to lower-voltage devices and at the same time protects less-ESD-resistant devices.

## Definition of threshold voltage

This document references a threshold voltage denoted as $V_{t h}$, which appears multiple times throughout this document when discussing the NFET between $\mathrm{V}_{\text {REF1 }}$ and $\mathrm{V}_{\text {REF2 }}$. The value of $\mathrm{V}_{\text {th }}$ is approximately 0.9 V at room temperature.

## Correct Device Set Up

In a normal set up shown in Figure 6.1, the enable pin and $\mathrm{V}_{\text {REF2 }}$ are shorted together and tied to a $200-\mathrm{k} \Omega$ resistor, and a reference voltage equal to $\mathrm{V}_{\text {REF1 }}$ plus the FET threshold voltage is established. This reference voltage is used to help pass lows from one side to another more effectively while still separating the different pull up voltages on both sides.

## Normal Setup



Figure 6.1 Normal Setup
Care should be taken to ensure $V_{\text {REF2 }}$ has an external resistor tied between it and $V_{C C 2}$. If $V_{\text {REF2 }}$ is tied directly to the $V_{C C 2}$ rail without a resistor, then there is no external resistance from the $\mathrm{V}_{\mathrm{CC2}}$ to $\mathrm{V}_{\mathrm{CC1}}$ to limit the current such as in Figure 6.2. This effectively looks like a low impedance path for current to travel through and potentially break the pass FET if the current flowing through the pass FET is larger than the absolute maximum continuous channel current specified in section 1.0. The continuous channel current is larger with a higher voltage difference between $\mathrm{V}_{\mathrm{CC} 1}$ and $\mathrm{V}_{\mathrm{CC} 2}$.

Figure 6.2 shows an improper set up. If $\mathrm{V}_{\mathrm{Cc}}$ is larger than $\mathrm{V}_{\mathrm{cc} 1}$ but less than $\mathrm{V}_{\mathrm{th}}$, the impedance between $\mathrm{V}_{\mathrm{cc} 1}$ and $\mathrm{V}_{\mathrm{Cc}}$ is high resulting in a low drain to source current, which does not cause damage to the device. Concern arises when $\mathrm{V}_{\mathrm{cc} 2}$ becomes larger than $\mathrm{V}_{\mathrm{cc1}}$ by $\mathrm{V}_{\mathrm{th}}$. During this event, the NFET turns on and begin to conduct current. This current is dependent on the gate to source voltage and drain to source voltage.


Figure 6.2 Abnormal Setup

## Disconnecting a Slave from the Main I2C Bus Using the EN Pin

NCA9306 can be used as a switch to disconnect one side of the device from the main $I^{2} \mathrm{C}$ bus. This can be advantageous in multiple situations. One instance of this situation is if there are devices on the $I^{2} \mathrm{C}$ bus which only supports fast mode ( 400 kHz ) while other devices on the bus support fast mode plus ( 1 MHz ). An example of this is displayed in Figure 4.1.3.


Figure 6.3 Example of an $I^{2} \mathrm{C}$ bus with multiple supported frequencies
In this situation, if the master is on the 1 MHz side then communicating at 1 MHz should not be attempted if NCA9306 were enabled. It needs to be disabled for NCA9306 to avoid possibly glitching state machines in devices which were designed to operate correctly at 400 kHz or slower. When NCA9306 is disabled, the master can communicate with the 1 MHz devices without disturbing the 400 kHz bus. When the NCA9306 is enabled, communication across both sides at 400 kHz is acceptable.

## Supporting Remote Board Insertion to Backplane with NCA9306

Another situation where NCA9306 is advantageous when using its enable feature is when a remote board with $I^{2} C$ lines needs to be attached to a main board (backplane) with an $I^{2} \mathrm{C}$ bus such as in Figure 6.4. If connecting a remote board to a backplane is not done properly, the connection could result in data corruption during a transaction or the insertion could generate an unintended pulse on the SCL line. Which could glitch an $I^{2} \mathrm{C}$ device state machine causing the $I^{2} \mathrm{C}$ bus to get stuck.


Figure 6.4 An example of connecting a remote board to a main board (backplane)
NCA9306 can be used to support this application because it can be disabled while making the connection. Then it is enabled once the remote board is powered on and the buses on both sides are IDLE.

## Switch Configuration

NCA9306 has the capability of being used with its $\mathrm{V}_{\text {REF1 }}$ voltage equal to $\mathrm{V}_{\text {REF2. }}$. This essentially turns the device from a translator to a device which can be used as a switch, and in some situations this can be useful. The switch configuration is shown in Figure 6.5 and translation mode is shown in Figure 6.6.


Figure 6.5 Switch Configuration


Translation Configuration:where VcC2>=Vref1+0.7V

Figure 6.6 Translation Configuration
When NCA9306 is in the switch configuration $\left(V_{\text {REF1 }}=V_{\text {REF2 }}\right)$, the propagation delays are different compared to the translator configuration. Taking a look at the propagation delays, if the pull up resistance and capacitance on both sides of the bus are equal, then in switch mode the NCA9306 has the same propagation delay from side one to two and side two to one. The propagation delays become lower when $\mathrm{V}_{\mathrm{CC} 1} / \mathrm{V}_{\mathrm{CC} 2}$ is larger. For example, the propagation delay at 1.8 V is longer than at 5 V in the switching configuration. When NCA9306 is in translation mode, side one propagates lows to side two faster than side two can propagate lows to side 1 . This time difference becomes larger the larger the difference between $V_{C C 2}$ and $V_{C C 1}$ becomes.

## Master on Side 1 or Side 2 of Device

$1^{2} \mathrm{C}$ and SMBus are bidirectional protocol meaning devices on the bus can both transmit and receive data. NCA9306 was designed to allow for signals to be able to be transmitted from either side, thus allowing for the master to be able to placed on either side of the device. Figure 4.1.7 shows the master on Side 1 or Side 2 of NCA9306.


Figure 6.7 Master on Side 1 or Side 2 of NCA9306

## LDO and NCA9306 Concerns

The $V_{\text {REF1 }}$ pin can be supplied by a low-dropout regulator (LDO), but in some cases the LDO may lose its regulation because of the bias current from $\mathrm{V}_{\text {REF } 2}$ to $\mathrm{V}_{\text {REF1 }}$. If the LDO cannot sink the bias current, then the current has no other paths to ground and instead charges up the capacitance on the $\mathrm{V}_{\text {REF1 }}$ node (both external and parasitic). This results in an increase in voltage on the $\mathrm{V}_{\text {REF1 }}$ node. If no other paths for current to flow are established (such as back biasing of body diodes or clamping diodes through other devices on the $\mathrm{V}_{\text {REF1 }}$ node), then the $\mathrm{V}_{\text {REF1 }}$ voltage ends up stabilizing when $\mathrm{V}_{\text {gs }}$ of the pass FET is equal to $\mathrm{V}_{\text {th }}$. This means $\mathrm{V}_{\text {REF1 }}$ node voltage is $\mathrm{V}_{\text {cC2 }}-\mathrm{V}_{\text {th }}$. Note that any slaves/masters running off of the LDO now see the $\mathrm{V}_{\mathrm{CC2}}-\mathrm{V}_{\mathrm{th}}$ voltage which may cause damage to those slaves/masters if they are not rated to handle the increased voltage.


Figure 6.8 Example of no leakage current path when using LDO
To ensure LDO does not lose regulation due to the bias current of NCA9306, a weak pull down resistor can be placed on $\mathrm{V}_{\text {REF1 }}$ to ground to provide a path for the bias current to travel. The recommended pull down resistor is calculated by Equation 4 where 0.75 gives about $25 \%$ margin for error incase bias current increases during operation.


Figure 6.9 Example with Leakage current path when using an LDO

$$
V_{\text {en }}=V_{\text {REF1 }}+V_{\text {th }}
$$

where

$$
\begin{align*}
& \mathrm{V}_{\text {th }} \text { is approximately } 0.9 \mathrm{~V}  \tag{1}\\
& \mathrm{I}_{\text {bias }}=\left(\mathrm{V}_{\text {cC2 }}-\mathrm{V}_{\text {en }}\right) / 200 \mathrm{k}  \tag{2}\\
& \mathrm{R}_{\text {pulldown }}=\mathrm{V}_{\text {out }} / \mathrm{Ibias}  \tag{3}\\
& \text { Recommended } \mathrm{R}_{\text {pulldown }}=\mathrm{R}_{\text {pulldown }} \times 0.75 \tag{4}
\end{align*}
$$

Current Limiting Resistance on VREF2
The resistor is used to limit the current between $\mathrm{V}_{\text {REF2 }}$ and $\mathrm{V}_{\text {REF1 }}$ (denoted as $\mathrm{R}_{\mathrm{CC}}$ ) and helps to establish the reference voltage on the enable pin. The 200k resistor can be changed to a lower value; however, the bias current proportionally increases as the resistor decreases.

$$
\begin{equation*}
I_{\text {bias }}=\left(V_{\mathrm{CC} 2}-V_{\text {en }}\right) / R_{\mathrm{cc}} \tag{5}
\end{equation*}
$$

where
$\mathrm{V}_{\text {th }}$ is approximately 0.9 V
$V_{\text {en }}=V_{\text {REF } 1}+V_{\text {th }}$
Keep in mind $R_{c c}$ should not be sized low enough that $I_{c c}$ exceeds the absolute maximum continuous channel current specified in Equation 6.

$$
\begin{equation*}
\mathrm{R}_{\mathrm{CC}(\text { min })} \geq\left(\mathrm{V}_{\mathrm{cC} 2}-\mathrm{V}_{\text {en }}\right) / 0.128 \tag{6}
\end{equation*}
$$

where
$\mathrm{V}_{\text {th }}$ is approximately 0.9 V
$\mathrm{V}_{\text {en }}=\mathrm{V}_{\text {REF1 }}+\mathrm{V}_{\text {th }}$

### 6.2. Functional Block Diagram



Figure 6.10 Block Diagram of NCA9306

### 6.3. Feature Description

## Enable (EN) Pin

The NCA9306 device is a double-pole, single-throw switch in which the gate of the transistors is controlled by the voltage on the EN pin. In Figure 7.1, the NCA9306 device is always enabled when power is applied to $\mathrm{V}_{\text {REF2. }}$. In Figure 7.2, the device is enabled when a control signal from a processor is in a logic-high state.

## Voltage Translation

The primary feature of the NCA9306 device is translating voltage from an $I^{2} \mathrm{C}$ bus referenced to $\mathrm{V}_{\text {REF }}$ up to an $I^{2} \mathrm{C}$ bus referenced to $\mathrm{V}_{\text {DPU }}$, to which $V_{\text {REF2 }}$ is connected through a $200-\mathrm{k} \Omega$ pullup resistor. Translation on a standard, open-drain $I^{2} \mathrm{C}$ bus is achieved by simply connecting pullup resistors from SCL1 and SDA1 to $\mathrm{V}_{\text {REF1 }}$ and connecting pullup resistors from SCL2 and SDA2 to $\mathrm{V}_{\text {DPU }}$.

## 7. Application Note

### 7.1. Application Information

## General Applications of I2C

As with the standard $I^{2} C$ system, pullup resistors are required to provide the logic-high levels on the translator bus. The size of these pullup resistors depends on the system, but each side of the repeater must have a pullup resistor. The device is designed to work with standard-mode and fast-mode ${ }^{2}$ C devices in addition to SMBus devices. Standard-mode I2C devices only specify 3 mA in a generic I2C system where standard-mode devices and multiple masters are possible. Under certain conditions, high termination currents can be used. When the SDA1 or SDA2 port is low, the clamp is in the ON state, and a low-resistance connection exists between the SDA1 and SDA2 ports. Assuming the higher voltage is on the SDA2 port when the SDA2 port is high, the voltage on the SDA1 port is limited to the voltage set by VREF1. When the SDA1 port is high, the SDA2 port is pulled to the pullup supply voltage of the drain (VDPU) by the pullup resistors. This functionality allows a seamless translation between higher and lower voltages selected by the user, without the need for directional control. The SCL1-SCL2 channel also functions in the same way as the SDA1-SDA2 channel.

### 7.2. Typical Application

Figure 7.1 and Figure 7.2 show how these pullup resistors are connected in a typical application, as well as two options for connecting the EN pin.


Figure 7.1 Typical Circuit (Switch Always Enabled)


Figure 7.2 Typical Application Circuit (Switch Enable Control)

### 7.3. Detailed Design Procedure

## Bidirectional Voltage Translation

For the bidirectional clamping configuration (higher voltage to lower voltage or lower voltage to higher voltage), the EN input must be connected to $\mathrm{V}_{\text {REF2 }}$ and both pins pulled to high-side $\mathrm{V}_{\text {DPU }}$ through a pullup resistor (typically $200 \mathrm{k} \Omega$ ). This allows $\mathrm{V}_{\text {REF2 }}$ to regulate the EN input. A 100-pF filter capacitor connected to VREF2 is recommended. The $I^{2} \mathrm{C}$ bus master output can be push-pull or open-drain (pullup resistors may be required) and the $I^{2} \mathrm{C}$ bus device output can be open-drain (pullup resistors are required to pull the SCL2 and SDA2 outputs to $V_{\text {DPU }}$. However, if either output is push-pull, data must be unidirectional or the outputs must be 3-state capable and be controlled by some direction-control mechanism to prevent high-to-low contentions in either direction. If both outputs are opendrain, no direction control is needed.

## Sizing Pullup Resistors

Figure 7.3 and Figure 7.4 respectively show the maximum and minimum pullup resistance allowable by the $I^{2} \mathrm{C}$ specification for standard-mode ( 100 kHz ) and fast-mode ( 400 kHz ) operation.


Figure 7.3 Maximum Pullup Resistance $\left(R_{p(\text { max }}\right)$ vs Bus Capacitance ( $C_{b}$ )


Figure 7.4 Minimum Pullup Resistance $\left(\mathrm{R}_{\mathrm{p}(\text { min })}\right)$ vs Pullup Reference Voltage ( $\mathrm{V}_{\text {Dpux }}$ )

## 8. Power Supply Recommendations

For supplying power to the NCA9306 device, the $\mathrm{V}_{\text {REF1 }}$ pin can be connected directly to a power supply. The $\mathrm{V}_{\text {REF2 }}$ pin must be connected to the $\mathrm{V}_{\text {DPU }}$ power supply through a $200-\mathrm{k} \Omega$ resistor. Failure to have a high impedance resistor between $\mathrm{V}_{\text {REF2 }}$ and $\mathrm{V}_{\text {DPU }}$ results in excessive current draw and unreliable device operation. It is also worth noting, that in order to support voltage translation, the NCA9306 must have the EN and $\mathrm{V}_{\text {REF2 }}$ pins shorted and then pulled up to $\mathrm{V}_{\text {DPU }}$ through a high-impedance resistor.

## 9. Layout

### 9.1. Layout Guidelines

For printed-circuit board (PCB) layout of the NCA9306 device, common PCB layout practices should be followed, but additional concerns related to high-speed data transfer such as matched impedances and differential pairs are not a concern for $I^{2} C$ signal speeds.

In all PCB layouts, it is a best practice to avoid right angles in signal traces, to fan out signal traces away from each other on leaving the vicinity of an integrated circuit (IC), and to use thicker trace widths to carry higher amounts of current that commonly pass through power and ground traces. The 100-pF filter capacitor should be placed as close to $\mathrm{V}_{\text {REF2 }}$ as possible. A larger decoupling capacitor can also be used, but a longer time constant of two capacitors and the $200-\mathrm{k} \Omega$ resistor results in longer turnon and turnoff times for the NCA9306 device.

These best practices are shown in Figure 9.1.
For the layout example provided in Figure 9.1, it would be possible to fabricate a PCB with only two layers by using the top layer for signal routing and the bottom layer as a split plane for power (VCC) and ground (GND). However, a four-layer board is preferable for boards with higher-density signal routing. On a four-layer PCB, it is common to route signals on the top and bottom layer, dedicate one internal layer to a ground plane, and dedicate the other internal layer to a power plane. In a board layout using planes or split planes for power and ground, vias are placed directly next to the surface-mount component pad, which must attach to VCC or GND, and the via is connected electrically to the internal layer or the other side of the board. Vias are also used when a signal trace must be routed to the opposite side of the board, but this technique is not demonstrated in Figure 9.1.


Figure 9.1 NCA9306 Layout Example

## 10. Package Information


$\underline{T O P ~ V I E W}$


SIDE VIEW


SIDE VIEW


* CONTROLUNG DIMENSION: MM

| SYMBOL | MILLIMETER |  |  |
| :---: | :---: | :---: | :---: |
|  | MIN. | NOM. | MAX. |
| A | --- | --- | 1.00 |
| A1 | 0.00 | --- | 0.15 |
| A2 | 0.60 | 0.75 | 0.85 |
| A3 | --- | 0.12 | --- |
| Q | 0.19 | 0.20 | 0.21 |
| b | 0.17 | 0.22 | 0.27 |
| c | 0.08 | --- | 0.23 |
| D | 1.90 | 2.00 | 2.10 |
| E | 2.20 | 2.30 | 2.40 |
| HE | 3.00 | 3.10 | 3.20 |
| e | 0.50 |  | bsc |
| L | 0.40 |  | bsc |
| L1 | 0.15 | --- | 0.40 |
| Y | --- | 0.10 | --- |
| V | --- | 0.20 | --- |
| w | --- | 0.08 | --- |
| Z | 0.10 | --- | 0.40 |
| 日 | 0 | --- | 8 |

Figure 10.1 VSSOP8 Package Shape and Dimension in millimeters and (inches)


Figure 10.2 TSSOP8 Package Shape and Dimension in millimeters and (inches)

## 11. Order information

| Part Number | Pins | Temperature | MSL | Package Type | Package Drawing |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | Package Qty

## 12. Documentation Support

| Part Number | Product Folder | Datasheet | Technical Documents | Isolator selection guide |
| :--- | :--- | :--- | :--- | :--- |
| NCA9306 | Click here | Click here | Click here | Click here |

## 13. Tape and Reel Information



SECTION Y-Y

| Ao | $2.25+/-0.1$ |
| :---: | :---: |
| Bo | $3.35+/-0.1$ |
| Ko | $1.40+/-0.1$ |
| K 1 | $1.00+/-0.1$ |
| F | $3.50+/-0.05$ |
| $\mathrm{P}_{1}$ | $4.00+/-0.1$ |
| W | $8.00+/-0.1$ |



Figure 12.1 Tape and Reel Information of VSSOP8


Figure 12.1 Tape and Reel Information of TSSOP8

## 14. Revision history

| Revision | Description | Date |
| :--- | :--- | :--- |
| 1.0 | Initial version | $2020 / 4 / 25$ |
| 1.1 | Added tape and reel information | $2020 / 7 / 1$ |
|  |  |  |

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NLSV4T3144MUTAG NLVSX4373MUTAG NB3U23CMNTAG NLSX3013BFCT1G NLSX3012DMR2G NLA9306MU3TCG
NVT2001GMZ P3A9606JKZ PCA9306DC1Z PI4ULS3V504AZMAEX NLVSV1T244MUTBG 74AXP1T34GWH HT7106ARQZ44
NJU7660AM-TE1 CLVC16T245MDGGREP CAVCB164245MDGGREP NTS0102DP-Q100H FXLA104UM12X FXMA2102UMX
PI4ULS5V201TAEX CD40109BPWR SY89321LMG-TR SY100ELT22ZG TXS0102DCTRE4 MC10H350FNG MC10H125FNR2G
MC100EPT21MNR4G MC100EP91DWG NLSX5014MUTAG NTB0101GS, 132 NTB0104UK-Q100Z GTL2012DP,118
74AVC1T45GN,132 NLSV2T244MUTAG NLSX3013FCT1G NLSX5011AMX1TCG PCA9306USG PTN3363BSMP


[^0]:    ${ }^{1}$ Translating down: the high-voltage side driving toward the low-voltage side

[^1]:    ${ }^{1}$ Translating up: the low-voltage side driving toward the high-voltage side

